ZIF-67-Metal–Organic-Framework-Based Triboelectric Nanogenerator for Self-Powered Devices

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Abstract: Energy harvesting from the ambient environment can be a beneficial and promising source for powering micro- and nanodevices. Triboelectric nanogenerator (TENG) technology has been proved to be a simple and cost-effective method to harness ambient mechanical energy. The performance of the TENG device mainly depends on the careful selection of the material pair. So far, metals and polymer materials have dominated TENG technology. Recently, there have been few reports on metal–organic framework (MoF)-based TENGs. MoFs are very interesting and offer excellent chemical and thermal stability, besides their unique properties, such as tunable pore size and high surface area. Herein, we report a zeolitic imidazole framework (ZIF-67)-based TENG device for self-powered device applications. We used ZIF-67 as one tribolayer, and PET and PMMA as opposite tribolayers. The output performance of the TENG device fabricated with the PMMA/ZIF-67 pair showed values of 300 V, 47.5 µA, and 593 mW/m² of open-circuit voltage, short-circuit current, and power density, respectively. To the best of our knowledge, these are the highest reported values so far for ZIF-67-based TENG devices. The fabricated TENG device lit up 250 LEDs and was employed to explore different self-powered device applications.

Keywords: triboelectric nanogenerator; metal–organic frameworks; mechanical energy harvesting; self-powered devices; ZIF-67

1. Introduction

In recent years, new technologies that harvest energy from the ambient environment as clean and sustainable energy at a low frequency have attracted a lot of attention. The need for alternative energy sources has become extremely important with the increased usage of sensor systems, wireless networks, and IoT-based devices. In 2018, the IoT-based systems in use were estimated at 50 billion, and they are expected to reach around 200 billion by 2025 [1]. All these network systems use many sensors and electronic circuits for different applications, such as health monitoring, wearable sensors, and self-powered devices. The minimum required power in the range of microwatts is essential to operate these electronic items [2,3]. Therefore, the ideal solution for providing sustainable, green, portable self-power to these large-scale sensors is scavenging energy from the ambient surroundings with energy-harvesting technologies. Scavenging energy from the ambient environment not only reduces the use of a large number of batteries but also provides an alternative solution for the size constraints of micro- and nanoscale IoT-based devices [4,5]. Several mechanical energy-harvesting methods, such as piezoelectric, triboelectric, and electromagnetic nanogenerators, already exist in the literature. Among all, triboelectric...
nanogenerators have been proved to be a cost-effective, highly efficient, flexible, and portable technique for the cleanest and most sustainable energy source to power these devices. Z.L. Wang’s research group introduced the TENG concept in 2012 [6]. The TENG works with the coupled effect of contact electrification (triboelectrification) and the electrostatic induction phenomenon [7–9]. In the triboelectrification process, charges are produced upon the physical contact between two dissimilar materials with opposite electron affinity [10]. Typical triboelectrification can only generate the accumulation of charges, but current is not generated, because there is no discharge process [2]. However, the TENG device uses the coupled effect of an electrostatic phenomenon with contact electrification to generate current. The triboelectric effect can be observed in a wide variety of materials, and there is no limitation on the material of choice. Therefore, researchers have been working on different suitable pairs of tribomaterials to generate maximum power efficiencies.

The search for new materials in TENG device design has recently grown considerably to improve the power density. The output performance parameters, such as voltage, short-circuit current, power density, and stability, are crucial parameters for optimizing a suitable TENG device. Currently, materials such as polymers and metals with known tribocharge density, dielectric constant, and other relevant parameters are widely used as triboelectric layers. However, these are just a small fraction of the existing materials [11]. The search for new materials gave surprising results, such as cellulose acetate, which was traditionally believed not to be a good tribomaterial until 2019 [12]. Other than cellulose, there are biopolymers [13], natural materials [14], bio-waste [15], plant-based materials [16], carbon-derived materials [17], 2D-layered materials [18], metal-oxide-based materials [19], and metal–organic frameworks [20] for exploring the energy-harvesting-based TENG devices. Among all the materials mentioned above, metal–organic framework (MoF)-based TENGs are not explored to their full potential in the literature. Recently, a large number of MoFs with zeolitic architectures have been successfully prepared as hybrid frameworks. Among them, zeolitic imidazole frameworks (ZIFs) have recently gained considerable attention due to their outstanding chemical and thermal stability. They possess a large surface area, an easily functional pore surface, adjustable pore size, and high crystallinity. ZIFs are a subclass of MoF materials with a special 3D network formed by coordination bonds between the metal ion (metal clusters) and an organic ligand. The unique properties of ZIFs have attracted numerous applications, such as gas storage, separation, liquid separation, catalysis, electrochemical sensing, storage, and battery applications [21–26]. Apart from direct applications, ZIFs are used as precursors and templates to derive functional and next-generation materials [27–30].

Researchers have started exploring energy-harvesting applications based on ZIFs. Khandelwal et al. reported ZIF-8-, ZIF-7-, ZIF-9-, ZIF-11-, ZIF-12-, and ZIF-62-based triboelectric nanogenerators [20,31–33]. G. Khandelwal et al. reported most of ZIF-based TENGs in the literature. In all the reports, ZIF films were created by attaching ZIF powder to the conducting glue placed on the aluminum substrate. The excess ZIF powder was removed using an argon air gun. Rayyan Ali et al. recently reported an MoF-5-based TENG device, and PTFE was used as an opposite triboelectric layer [34]. Chao Huang et al. reported a bimetallic Zn/Co-MoF-based TENG device with PVDF as a negative triboelectric layer [35]. Sugato Hajra et al. reported a ZIF-67-based TENG device with different negative triboelectric layers, such as Teflon, PDMS, and paper [36]. They used a multi-unit S-shaped device prepared with ZIF-67 particles. The device with Teflon as another triboelectric layer showed a peak-to-peak output voltage of 118 V, a current of 1.7 µA, and a power density of about 150 mW/m². The low output power density may have been due to the pressed ZIF-67 powder on the copper tape, and the pressed ZIF-67 film may have provided a less effective contact area during the TENG operation. Furthermore, the opposite triboelectric layer with ZIF-67 is also a crucial parameter in deciding the TENG performance.

The performances of TENG devices based on different MoFs are summarized in Table 1. In this work, we report a TENG device based on ZIF-67 as a positive trboelectric layer.
and PMMA as a negative triboelectric layer. To the best of our knowledge, this tribopair is reported for the first time. The novelty of the manuscript lies in the study of ZIF-67 and PMMA in TENG applications for the first time and in reporting the highest power density so far. The ZIF-67 and PMMA pair showed an outstanding power output and excellent stability. Compared with other reports, the simple ZIF-67- and PMMA-based TENG device showed an output voltage of 300 V, a current of 47.5 µA, and a power density of 593 mW/m².

The improvement in the output performance of the device may be attributed to the large surface area of the ZIF-67 thin film. We deposited ZIF-67 powder as a thin film on the aluminum substrate rather than using ZIF-67 powder directly as reported by Hazara et al. Thin-film deposition dramatically enhanced the surface characteristics and contact points for the electrification process and improved the device stability [37]. This manuscript adopted a cost-effective, straightforward, single-step approach for TENG fabrication compared with the existing complex and expensive 3D-printing-based ZIF-67 TENG devices reported. The obtained power density of the ZIF-67/PMMA-based TENG device is the highest so far among all ZIF-based devices.

Table 1. Comparison of ZIF-based TENG device performances reported in the literature.

<table>
<thead>
<tr>
<th>S. No.</th>
<th>Positively Charged Material</th>
<th>Negatively Charged Material</th>
<th>Voltage</th>
<th>Current</th>
<th>Power Density</th>
</tr>
</thead>
<tbody>
<tr>
<td>1</td>
<td>ZIF-67</td>
<td>Teflon</td>
<td>118 V (peak to peak)</td>
<td>1.7 µA</td>
<td>150 mW/m²²</td>
</tr>
<tr>
<td>2</td>
<td>MIL-88A</td>
<td>FEP</td>
<td>80 V</td>
<td>2.2 µA</td>
<td>16.2 mW/m²²</td>
</tr>
<tr>
<td>3</td>
<td>ZIF-8</td>
<td>Kapton</td>
<td>164 V</td>
<td>7 µA</td>
<td>392 mW/m²²</td>
</tr>
<tr>
<td>4</td>
<td>ZIF-62</td>
<td>Teflon</td>
<td>62 V</td>
<td>1.4 µA</td>
<td>9.68 mW/m²²</td>
</tr>
<tr>
<td>5</td>
<td>ZIF-8 (HG)</td>
<td>Kapton</td>
<td>150 V</td>
<td>3.6 µA</td>
<td>6 µW (power)</td>
</tr>
<tr>
<td>6</td>
<td>ZIF-11</td>
<td>Kapton</td>
<td>27 V</td>
<td>0.3 µA</td>
<td>~1.3 mW/m²²</td>
</tr>
<tr>
<td>7</td>
<td>ZIF-12</td>
<td>Kapton</td>
<td>42 V</td>
<td>1 µA</td>
<td>~2.3 mW/m²²</td>
</tr>
<tr>
<td>8</td>
<td>ZIF-9</td>
<td>Kapton</td>
<td>29 V</td>
<td>0.5 µA</td>
<td>~0.9 mW/m²²</td>
</tr>
<tr>
<td>9</td>
<td>ZIF-7</td>
<td>Kapton</td>
<td>60 V</td>
<td>2 µA</td>
<td>~5.6 mW/m²²</td>
</tr>
<tr>
<td>10</td>
<td>Alpha cyclodextrin</td>
<td>Teflon</td>
<td>152 V (peak to peak)</td>
<td>1.2 µA</td>
<td>8 µW/cm²²</td>
</tr>
<tr>
<td>11</td>
<td>Beta cyclodextrin</td>
<td>Teflon</td>
<td>90 V (peak to peak)</td>
<td>0.52 µA</td>
<td>-</td>
</tr>
<tr>
<td>12</td>
<td>Gamma cyclodextrin</td>
<td>Teflon</td>
<td>116 V (peak to peak)</td>
<td>1.7 µA</td>
<td>-</td>
</tr>
<tr>
<td>13</td>
<td>ZIF-67</td>
<td>PMMA</td>
<td>300 V</td>
<td>47.5 µA</td>
<td>593 mW/m²²</td>
</tr>
</tbody>
</table>

In this work, ZIF-67-based TENGs were fabricated with a simple and cost-effective method. The fabricated TENGs were explored for self-powered device applications.

2. Materials and Methods
2.1. Synthesis of ZIF-67 Powder

All the chemicals used for synthesizing the ZIF-67 metal–organic framework were purchased from Sigma Aldrich and used without further modification. We followed the ZIF-67 synthesis procedure reported in the literature [40]. To summarize, 450 mg of cobalt nitrate hexahydrate [Co(NO₃)₂·6H₂O] was first dissolved in 3 mL of deionized water, which we labeled solution 1. Solution 2 was independently prepared by dissolving 5.5 g of 2-methylimidazole (Hmim) in 20 mL of deionized water. These two solutions were vigorously mixed for 6 h at room temperature; then, the resultant purple-colored precipitate was collected after centrifuging at 8000 rpm and washed carefully with water and methanol three times. Finally, the precipitant was vacuum-dried at 80 °C for 24 h to obtain ZIF-67 powder. The detailed procedure of ZIF-67 powder synthesis is depicted in Figure 1a.
nitrate hexahydrate $[\text{Co(NO}_3\text{)}_2 \cdot 6\text{H}_2\text{O}]$ was first dissolved in 3 mL of deionized water, which we labeled solution 1. Solution 2 was independently prepared by dissolving 5.5 g of 2-methylimidazole (Hmim) in 20 mL of deionized water. These two solutions were vigorously mixed for 6 h at room temperature; then, the resultant purple-colored precipitate was collected after centrifuging at 8000 rpm and washed carefully with water and methanol three times. Finally, the precipitant was vacuum-dried at 80 °C for 24 h to obtain ZIF-67 powder. The detailed procedure of ZIF-67 powder synthesis is depicted in Figure 1a.

2.2. Preparation of ZIF-67 Films

ZIF-67 was deposited on aluminum (Al) substrate using the doctor blade coating technique. Before the deposition of ZIF-67, the Al substrate was cleaned with acetone and deionized water in an ultrasonication bath for 5 min. The as-prepared ZIF-67 powder was mixed (0.2 g) in Polyvinyl alcohol (PVA) (5 mL), and the mixture was stirred continuously for one hour to obtain a homogeneous solution. The mixed solution was initially dropped on the Al substrate, and a spreader was driven through the solution at a blade speed of 30 mm/sec to obtain ZIF-67 thin films on the Al substrate. The schematic of the film preparation, actual photographs of the ZIF-67 solution dissolved in PVA, and ZIF-67 thin film on Al substrate are shown in Figure 1b.

2.3. Characterization of ZIF-67

The obtained ZIF-67 powder was characterized using X-ray diffraction (XRD; Bruker D8), and the surface functional groups were confirmed with FTIR spectroscopy (FTIR Bruker alpha II); the morphology of ZIF-67 was studied using scanning electron microscopy (SEM, ZEISS), and the thickness of ZIF-67 was measured using an optical microscope (Olympus BX53).

2.4. Fabrication of TENG Device

The schematic of TENG device fabrication is shown in Figure 1c. The aluminum and ITO substrates were used for the top and bottom electrodes. The ZIF-67 film on the Al substrate and the PET surface of ITO/PET substrate were used as two frictional layers and attached to a cardboard/acrylic base, as shown in Figure 1c. Four sponge spacers were placed between the supporting bases to maintain the distance of ~ 1cm between the frictional layers. The overall structure of the TENG device was Al/ZIF-67/PET/ITO.
output voltage of the TENG device was recorded using a digital oscilloscope (Tektronix TBS1102) with the aid of interface software (Tekvisa) using a computer. The short-circuit current of the TENG was measured using a low-noise current amplifier (Stanford Research SR570). The TENG device was tested at a hand-tapping frequency of ~3–4 Hz. Furthermore, we investigated the effect of hand-tapping frequency, different dimensions of the device, and different frictional layers while keeping ZIF-67 constant on the TENG performance. Finally, the stability and durability of the TENG devices were tested over a long period and with a large number of test cycles.

3. Results and Discussion

The crystalline and structural properties of as-prepared ZIF-67 film were characterized with XRD studies, and the corresponding XRD spectrum is shown in Figure 2a. The sharp and highly intense peaks suggest the highly crystalline nature of the synthesized ZIF-67. The experimental data were fitted with the Rietveld refinement method using Full-Profit software by assuming the cubic crystal structure to have a space group of I\(^{43}\) m. The refined lattice and Rietveld parameters are given in Table S1 (see Supplementary Information (SI), S1). The observed crystal structure was in single-phase formation, and no impurity phases were detected. The obtained ZIF-67 film XRD pattern was consistent with those in the previously reported literature [41–43].

![Figure 2a](image.png)

**Figure 2.** (a) XRD studies of ZIF-67 and Rietveld refinement analysis, (b) simulated ZIF-67 structure, (c) FTIR spectrum of ZIF-67 crystal, and (d–f) SEM images of synthesized ZIF-67 at high and low magnifications.
The as-synthesized ZIF-67 and organic linker 2-methyl imidazole (MIM) were characterized with FTIR to determine the material’s chemical composition and bonding information and are presented in Figure 2b. The peak observed in the MIM spectrum at 1842 cm$^{-1}$ was due to the -N-H group; the same was absent in the ZIF-67 spectra, strongly suggesting the successful coordination of Co and the -N-H group of MIM [44]. Moreover, a broad peak ranging from 3400 cm$^{-1}$ to 2200 cm$^{-1}$ centered at 2600 cm$^{-1}$ was attributed to the presence of the N-H-N hydrogen bond. The FTIR spectrum of ZIF-67 showed the absence of the broad hump, also confirming ZIF-67 structure formation and the completely deprotonated MIM linkers [45]. The intense bands ranging from 1300 cm$^{-1}$ to 1500 cm$^{-1}$ were attributed to the characteristic imidazole ring stretching. The peaks appearing at 1596 cm$^{-1}$ and 757 cm$^{-1}$ were attributed to the C = N stretching vibrations and out-of-plane bending modes, respectively [46]. The new absorption peak arising at 426 cm$^{-1}$ attributed to the Co-N stretching vibration of ZIF-67 was consistent with the previously reported literature results [47]. Figure 2d–f show the surface morphology of as-synthesized ZIF-67 film at high and low magnifications. The sphere-shaped ZIF-67 particles were observed uniformly all over the substrate. The observed morphology of ZIF-67 particles was similar to the reported literature results [48,49].

The mechanical energy conversion of the fabricated TENG ($10 \times 10$ cm$^2$) was tested against hand tapping. The TENG device size was $10 \times 10$ cm$^2$; the spacing between the two triboelectric layers was maintained at 1 cm, and the tapping frequency was maintained at ~3–4 Hz. Figure 3a,b show the open-circuit output voltage and short-circuit current of a ZIF-67-based TENG device in the switching polarity test. In the switching polarity test, the TENG device connections were interchanged at the input of the measuring instrument to confirm whether the response came from the device or instrument noise [50,51]. It is clear from Figure 3a,b that the electrical output came from the TENG device. The TENG device generated the average voltage and current of ~100 V and ~35 µA, respectively, in both forward and reversed connections. The working mechanism of the ZIF-67-based TENG in vertical contact separation mode is presented in Supplementary Information S2. The TENG device electrical output was recorded for different load resistance values to find out the maximum power density. The behaviors of the TENG output voltage and current are presented in Figure 3c. The output voltage increased with the increase in load resistance and saturated after 60 MΩ. This behavior was consistent with the other reported literature results [52–54]. At the same time, the current decreased with the increase in the external load due to ohmic losses. Furthermore, the instantaneous power density was calculated from Figure 3c and presented in Figure 3d. The instantaneous power density was calculated using the $P = (VI/A)$ formula, where $I =$ current, $V =$ voltage, and $A =$ active area of the device [55–57]. Initially, the instantaneous power density increased with load resistance and reached the maximum value of ~81.9 mW/m$^2$ at a 4 MΩ load resistance and then decreased at greater load resistances. The observed maximum instantaneous power density at 4 MΩ load resistance can be understood with the maximum power transfer theorem [58,59]. When the TENG device’s internal resistance matched the load resistance, it exhibited the maximum power density. The stability of the TENG device was tested for 15,000 cycles using a linear motor at a tapping frequency of ~4 Hz. The stability of the device was tested continuously for 60 min with the linear motor (1 min, ~240 cycles). The response of the TENG device was recorded every 10th min for 1 h, and the results are presented in Figure 4a (see Supplementary Video, S1). The TENG output voltage exhibited a stable response for 15,000 cycles, showing the device’s exceptional durability and mechanical stability.
The short-circuit current and open-circuit output voltages in different conditions were attributed to the enhanced contact area. The increase in the contact area produced a greater triboelectrification of charges, which resulted in greater current and voltage. The behavior of TENGs with the different active areas is well supported by the reported literature [60–62]. It is necessary to convert the AC output of a TENG to DC output to store in a capacitor. We used an IC DB 107 full-wave rectifier to convert the AC output into DC output. The device's effective size (size of frictional layers) plays a vital role in the output response at different external loads, and it exhibited the maximum power density. The stability of the TENG device was tested for 60 min with the linear motor (1 min, ~240 cycles). The stability of the TENG device was tested for 60 min with the linear motor (1 min, ~240 cycles). The stability of the TENG device was tested for 60 min with the linear motor (1 min, ~240 cycles). The stability of the TENG device was tested for 60 min with the linear motor (1 min, ~240 cycles). The stability of the TENG device was tested for 60 min with the linear motor (1 min, ~240 cycles).

Figure 3. (a) Forward and reverse current, (b) forward and reverse voltage, (c) voltage and current response at different external loads, and (d) power density vs. load resistance of the TENG device (all the measurements were recorded considering a device area of $10 \times 10 \text{cm}^2$).

Figure 4. Stability of the TENG device ($10 \times 10 \text{cm}^2$): (a) TENG electrical characteristics with different sizes of the frictional layer, (b) short-circuit current, (c) open-circuit voltage, (d) charging curves for different capacitors, (e) stored charge curves of different load capacitors as a function of time, (f) output voltage and stored charges behavior as a function of the load capacitance, (g) the maximum stored energy as a function of the load capacitance, (h) output voltage response of TENG device with different top triboelectric layers and ZIF-67 as the bottom triboelectric layer (Al/ZIF-67/PMMA/Al TENG device), (i) output voltage response, (j) output current response, (k) voltage and current response with load resistant variation, and (l) power density variation with different load resistance (all the measurements were recorded considering a device area of $10 \times 10 \text{cm}^2$).
The device’s effective size (size of frictional layers) plays a vital role in the output performance of a TENG device. We chose three sizes for the TENG device: 5 × 5, 7 × 7, and 10 × 10 cm² (effective area). The short-circuit current and open-circuit output voltages increased with the device size, as shown in Figure 4b,c. The current value increased from ~10.5 µA to ~35 µA, and the voltage increased from 35 V to 100 V. The increase in the current and voltage was attributed to the enhanced contact area. The increase in the contact area produced a greater triboelectrification of charges, which resulted in greater current and voltage. The behavior of TENGs with the different active areas is well supported by the reported literature [60–62]. It is necessary to convert the AC output of a TENG to the DC output to store in a capacitor. We used an IC DB 107 full-wave rectifier to convert the AC output into the DC output and charged different load capacitors with the continuous operation of the TENG for 5 min. Figure 4d illustrates the charging voltage curves of different load capacitors (C_L) of 1 µF, 2.2 µF, 47 µF, 100 µF, 220 µF, and 470 µF. We investigated the stored voltage, charge, and energy as a function of different load capacitors. As shown in Figure 4d, the 1 µF capacitor showed excellent charging capability, and it charged up to 13.4 V within 20 s and then increased slowly to the saturated voltage of 19.7 V in 220 sec, a behavior which is in agreement with earlier reports [31,33,51]. With a smaller C_L, the charging pace was faster, and the time until the voltage reached saturation was shorter. The charge stored on these varied capacitors was estimated by multiplying the charged voltage (V) by the capacitance (C_L), and the results are presented in Figure 4e. In Figure 4f, the values of charged voltage and stored charge are illustrated as functions of various load capacitance values. With respect to the load capacitor, the behavior of charged voltage and stored charge was opposite in nature. Furthermore, we calculated the energy stored in the capacitors as follows: E = ½CV², where V is saturated charged voltage. The variation in the maximum stored energy as a function of C_L is shown in Figure 4g. At an optimum load capacitance (C_L) of 100 µF, the maximum stored energy was found to be around 1800 µJ.

Furthermore, different TENG devices were prepared by keeping ZIF-67 as one constant triboelectric layer, and other triboelectric layers such as Kapton, Teflon, Silicone, and overhead projector (OHP) PET, and PMMA sheets were selected. Figure 4h shows the output voltages of the fabricated TENG devices with different triboelectric layers in combination with ZIF-67. It was observed that PMMA showed the highest output voltage (~300 V) with ZIF-67 as a triboelectric pair. Furthermore, we studied the electrical characteristics of the best TENG device (ZIF-67-PMMA) and explored its different applications. The open-circuit output voltage and short-circuit current of Al/ZIF-67/PMMA/Al was tested by switching the polarity of the geometry, and we found the same response as shown in Figure 4i,j, respectively. Furthermore, the TENG load characteristics and instantaneous power density are presented in Figure 4k,l. The highest power density of 593 mW/m² at 8 MΩ was observed, and it is the highest reported value so far for a metal–organic-framework-based TENG device to the best of our knowledge (Table 1). The highest power density may have been due to the triboelectric pair of ZIF-67 and PMMA. The power density of the TENG strongly depended on the triboelectric pair selection, which is evidenced in Figure 4h. Triboelectric films with a large work function difference can be expected to have a higher power density [63,64]. In addition to the above, the effective contact area between triboelectric films plays a significant role in deciding the TENG performance [65–67].

4. Applications of the TENG (ZIF-67-PMMA)

Self-powered electronic device applications were explored with the TENG (ZIF-67/PMMA). Figure 5a,b show the photographs of portable electronic devices (calculator, digital watch, and digital thermometer), a series connected 250 LEDs, an electroluminescence (EL) device, and a commercial hygrometer connected to the TENG in the OFF and ON conditions, respectively. The electroluminescence (EL) device was fabricated with the help of two conducting tin-doped indium oxide electrodes used for contact, and luminescent active materials (ZnS-Cu, Al) were sandwiched between two ITO electrodes. The output of
the TENG was sufficient to turn on the calculator, the digital watch, the digital thermometer, the connected series of 250 LEDs, and the EL device (see Supplementary Information Videos S2–S4). However, the hygrometer was not turned on with the TENG output due to the high power required by a large LCD. We stored energy provided by the TENG in a capacitor, which was used to switch on the hygrometer (see Supplementary Information Video S6).

Figure 5. Photographs of the various portable devices, EL device, and hygrometer powered with the ZIF-67-based TENG: (a) OFF state and (b) ON state.

5. Conclusions

This work presents high-performance ZIF-67-based TENGs and their application in self-powered devices. The best TENG device consisted of ZIF-67 and PMMA as triboelectric layers, and it exhibited an output voltage of ~300 V and a 47.5 µA short-circuit current. The highest power density of 593 mW/m² was reported in this manuscript, which is the highest among the ZIF-based TENGs reported so far. The fabricated device could switch on different portable electronic devices without any storage element. The power density of the TENG could be further enhanced with the help of different surface modification methods. The present work involves a simple, cost-effective design that can easily be scaled to large areas.

Supplementary Materials: The following supporting information can be downloaded at: https://www.mdpi.com/article/10.3390/nanoenergyadv2040015/s1, Table S1: The Rietveld refined lattice parameters of ZIF-67 and Rp, Rwp, and the goodness-of-fit (χ²) values of the fitting. Video S1: Operation of a calculator with the output power of the ZIF-67-based TENG device, Video S2: Operation of a digital watch with the output power of the ZIF-67-based TENG device, Video S3: Operation of a thermometer with the output power of the ZIF-67-based TENG device, Video S4: Lighting of 250 LEDs with the output power of the ZIF-67-based TENG device, Video S5: Operation of an electroluminescence device with the output power of the ZIF-67-based TENG device, Video S6: Operation of a digital hygrometer with the output power of the ZIF-67-based TENG device. Figure S1: Schematic illustration of the working mechanism of TENG.

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